

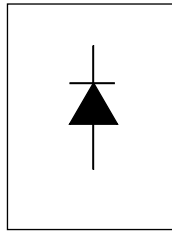
INPUT RECTIFIER DIODE

Description/Features

The 10ETS.. rectifier **SAFEIR** series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150°C junction temperature.

The **High Reverse Voltage** range available allows design of input stage primary rectification with **Outstanding Voltage Surge** capability.

Typical applications are in input rectification and these products are designed to be used with International Rectifier Switches and Output Rectifiers which are available in identical package outlines.



$$V_F < 1.1V @ 10A$$

$$I_{FSM} = 200A$$

$$V_{RRM} 800 \text{ to } 1600V$$

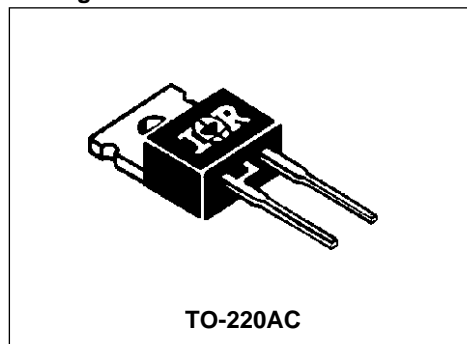
Output Current in Typical Applications

Applications	Single-phase Bridge	Three-phase Bridge	Units
Capacitive input filter $T_A=55^\circ C, T_J=125^\circ C$ common heatsink of $1^\circ C/W$	12.0	16.0	A

Major Ratings and Characteristics

Characteristics	10ETS..	Units
$I_{F(AV)}$ Sinusoidal waveform	10	A
V_{RRM}	800 to 1600	V
I_{FSM}	200	A
V_F @ 10A, $T_J=25^\circ C$	1.1	V
T_J	-40 to 150	$^\circ C$

Package Outline



Also available in D-pak (8EWS Series)

Voltage Ratings

Part Number	V_{RRM} , maximum peak reverse voltage V	V_{RSM} , maximum non repetitive peak reverse voltage V	I_{RRM} 150°C mA
10ETS08	800	900	0.5
10ETS12	1200	1300	
10ETS16	1600	1700	

Provide terminal coating for voltages above 1200V

Absolute Maximum Ratings

Parameters	10ETS..	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	10	A	@ $T_C = 105^\circ\text{C}$, 180° conduction half sine wave
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	170	A	10ms Sine pulse, rated V_{RRM} applied
	200		10ms Sine pulse, no voltage reapplied
I^2t Max. I^2t for fusing	130	A^2s	10ms Sine pulse, rated V_{RRM} applied
	145		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	1450	$\text{A}^2\sqrt{\text{s}}$	$t = 0.1$ to 10ms, no voltage reapplied

Electrical Specifications

Parameters	10ETS..	Units	Conditions
V_{FM} Max. Forward Voltage Drop	1.1	V	@ 10A, $T_J = 25^\circ\text{C}$
r_t Forward slope resistance	20	$\text{m}\Omega$	$T_J = 150^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.82	V	
I_{RM} Max. Reverse Leakage Current	0.05	mA	$T_J = 25^\circ\text{C}$
	0.50		$T_J = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

Thermal-Mechanical Specifications

Parameters	10ETS..	Units	Conditions
T_J Max. Junction Temperature Range	-40 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-40 to 150	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case	2.5	$^\circ\text{C}/\text{W}$	DC operation
R_{thJA} Max. Thermal Resistance Junction to Ambient	62	$^\circ\text{C}/\text{W}$	
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.5	$^\circ\text{C}/\text{W}$	Mounting surface, smooth and greased
w_t Approximate Weight	2(0.07)	g(oz.)	
T Mounting Torque	Min.	6(5)	Kg-cm (lbf-in)
	Max.	12(10)	
Case Style	TO-220AC		

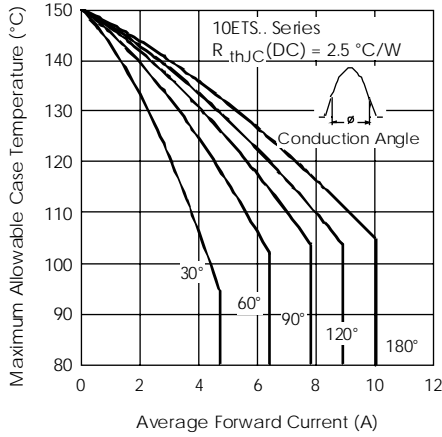


Fig. 1 - Current Rating Characteristics

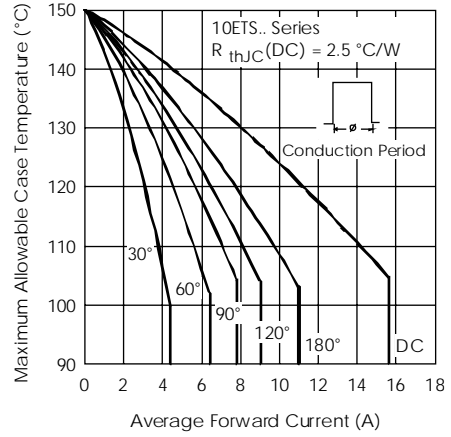


Fig. 2 - Current Rating Characteristics

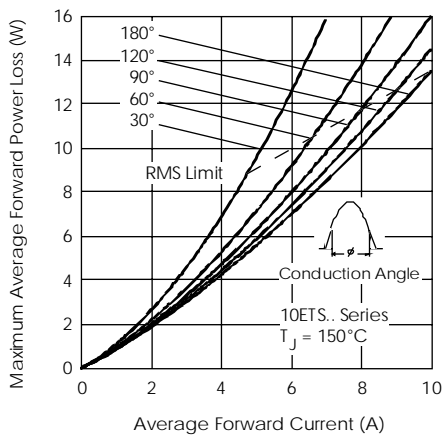


Fig. 3 - Forward Power Loss Characteristics

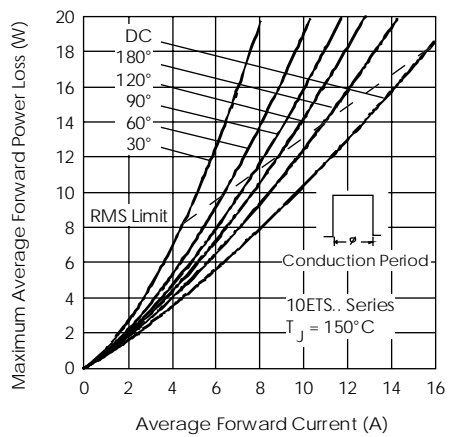


Fig. 4 - Forward Power Loss Characteristics

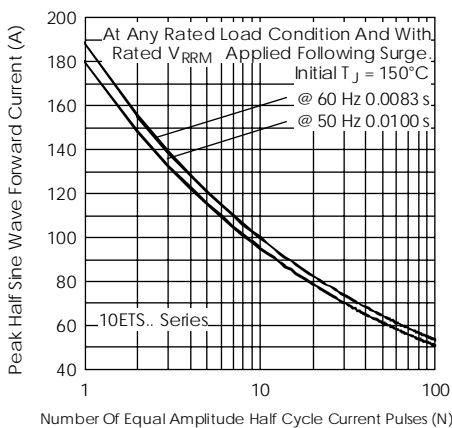


Fig. 5 - Maximum Non-Repetitive Surge Current

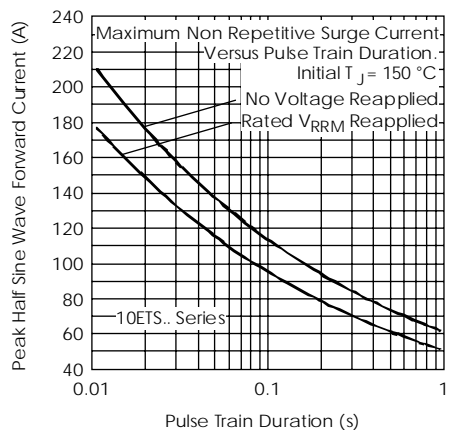


Fig. 6 - Maximum Non-Repetitive Surge Current

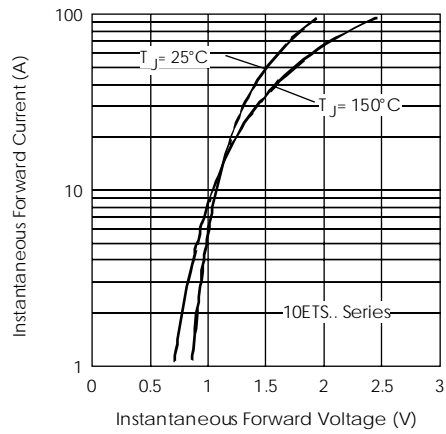


Fig.8-Forward Voltage Drop Characteristics

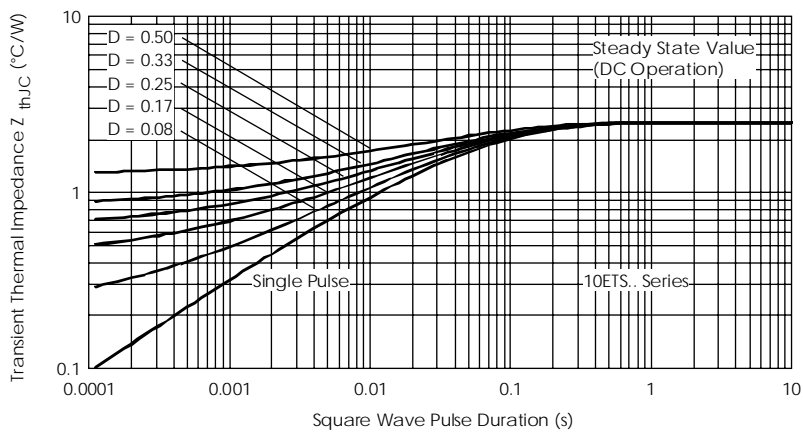


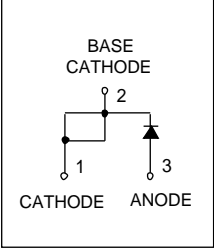
Fig.9- Thermal Impedance Z_{thjC} Characteristics

Ordering Information Table

Device Code

10	E	T	S	16
①	②	③	④	⑤

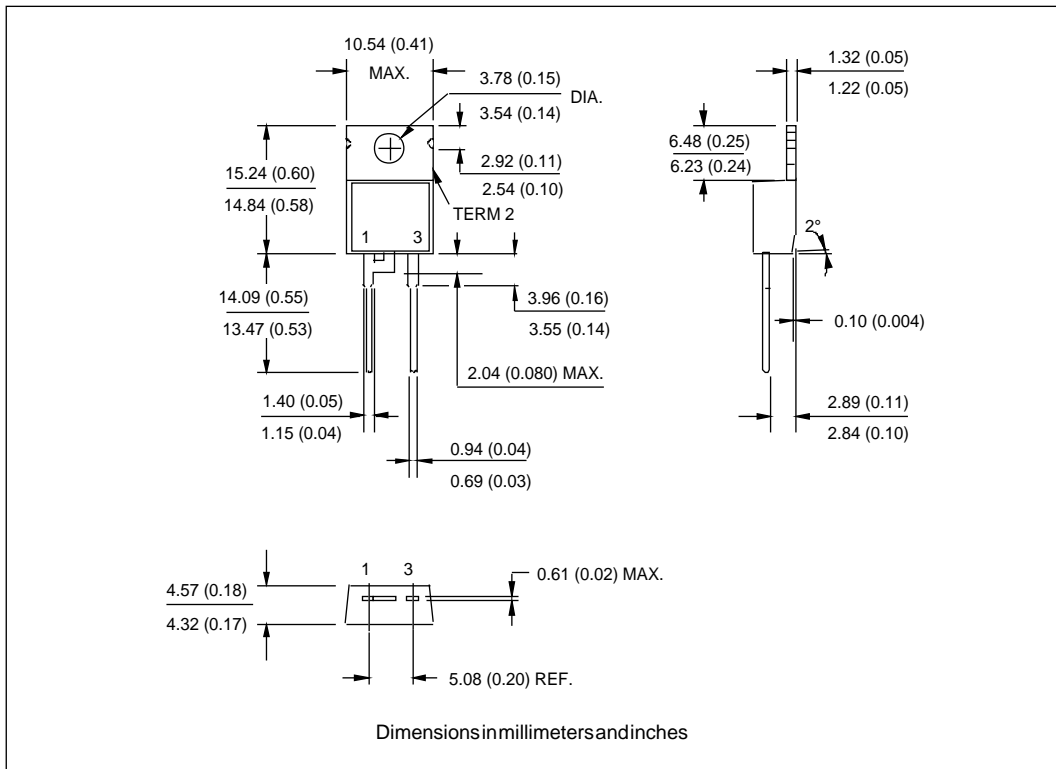
10 = Voltage Rating Code: x 100 = V
E = Standard Recovery Rectifier
T = Standard Recovery Rectifier
S = Standard Recovery Rectifier
16 = Standard Recovery Rectifier



08 = 800V
12 = 1200V
16 = 1600V

RRM ———

Outline Table





Notice

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